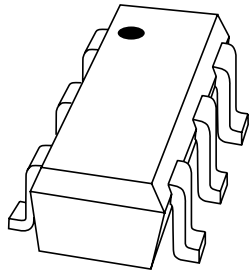


# DATA SHEET



## **BGA2717** MMIC wideband amplifier

Preliminary specification

2004 Feb 02

## MMIC wideband amplifier

## BGA2717

## FEATURES

- Internally matched to 50  $\Omega$
- Wide frequency range (3.2 GHz at 3 dB bandwidth)
- Flat 24 dB gain ( $\pm 1$  dB up to 2.8 GHz)
- -2.5 dBm output power at 1dB compression point
- Good linearity for low current (  $IP3_{(out)} = 10$  dBm)
- Low second harmonic, -38 dBc at  $P_{Drive} = -40$  dBm
- Low noise figure, 2.3 dB at 1 GHz
- Unconditionally stable ( $K \geq 2$ ).

## APPLICATIONS

- LNB IF amplifiers
- Cable systems
- ISM
- General purpose.

## DESCRIPTION

Silicon Monolithic Microwave Integrated Circuit (MMIC) wideband amplifier with internal matching circuit in a 6-pin SOT363 SMD plastic package.

## QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
$V_S$	DC supply voltage		5	6	V
$I_S$	DC supply current		8.0	-	mA
$ s_{21} ^2$	insertion power gain	$f = 1$ GHz	24	-	dB
NF	noise figure	$f = 1$ GHz	2.3	-	dB
$P_{L(sat)}$	saturated load power	$f = 1$ GHz	1	-	dBm

## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134)

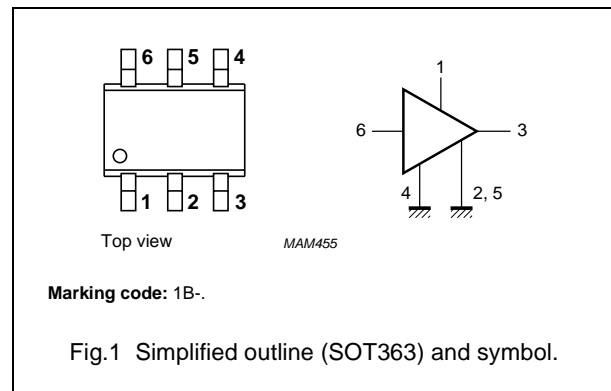
SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_S$	DC supply voltage	RF input AC coupled	-	6	V
$I_S$	supply current		-	15	mA
$P_{tot}$	total power dissipation	$T_s \leq 90$ °C	-	200	mW
$T_{stg}$	storage temperature		-65	+150	°C
$T_j$	operating junction temperature		-	150	°C
$P_D$	maximum drive power		-	-10	dBm

## CAUTION

This product is supplied in anti-static packing to prevent damage caused by electrostatic discharge during transport and handling.

## PINNING

PIN	DESCRIPTION
1	$V_S$
2, 5	GND2
3	RF out
4	GND1
6	RF in



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## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-s}$	thermal resistance from junction to solder point	$P_{tot} = 200\text{ mW}; T_s \leq 90\text{ }^\circ\text{C}$	300	K/W

## CHARACTERISTICS

$V_S = 5\text{ V}; I_S = 8\text{ mA}; T_j = 25\text{ }^\circ\text{C};$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$I_S$	supply current		6	8.0	10	mA
$ s_{21} ^2$	insertion power gain	f = 100 MHz	18	18.6	20	dB
		f = 1 GHz	23	23.9	25	dB
		f = 1.8 GHz	24	25.0	27	dB
		f = 2.2 GHz	24	25.1	27	dB
		f = 2.6 GHz	22	24.0	26	dB
		f = 3 GHz	20	22.1	24	dB
$R_{L\ IN}$	return losses input	f = 1 GHz	15	19	–	dB
		f = 2.2 GHz	8	9.4	–	dB
$R_{L\ OUT}$	return losses output	f = 1 GHz	8	10	–	dB
		f = 2.2 GHz	5	6.8	–	dB
$ s_{12} ^2$	isolation	f = 1.6 GHz	54	55	–	dB
		f = 2.2 GHz	38	39	–	dB
NF	noise figure	f = 1 GHz	–	2.3	2.5	dB
		f = 2.2 GHz	–	2.9	3.1	dB
BW	bandwidth	at $ s_{21} ^2 -3\text{ dB}$ below flat gain at 1 GHz	3	3.2	–	GHz
K	stability factor	f = 1 GHz	–	13	–	–
		f = 2.2 GHz	–	1.7	–	–
$P_{L(sat)}$	saturated load power	f = 1 GHz	0	1.4	–	dBm
		f = 2.2 GHz	–1	0.1	–	dBm
$P_{L\ 1\ dB}$	load power	at 1 dB gain compression; f = 1 GHz	–4	–2.6	–	dBm
		at 1 dB gain compression; f = 2.2 GHz	–5	–3.1	–	dBm
IM2	second order intermodulation	at $P_D = -40\text{ dBm}, f_0 = 1\text{ GHz}$	36	38	–	dBc
IP3(in)	input intercept point	f = 1 GHz	–15	–13.9	–	dBm
		f = 2.2 GHz	–20	–18.8	–	dBm
IP3(out)	output intercept point	f = 1 GHz	9	10.0	–	dBm
		f = 2.2 GHz	4	6.3	–	dBm

# MMIC wideband amplifier

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## APPLICATION INFORMATION

Figure 2 shows a typical application circuit for the BGA2717 MMIC. The device is internally matched to 50 Ω, and therefore does not need any external matching. The value of the input and output DC blocking capacitors C2 and C3 should not be more than 100 pF for applications above 100 MHz. However, when the device is operated below 100 MHz, the capacitor value should be increased.

The 22 nF supply decoupling capacitor C1 should be located as closely as possible to the MMIC.

The PCB top ground plane, connected to the pins 2,4 and 5 must be as close as possible to the MMIC, preferably also below the MMIC. When using via holes, use multiple via holes, as close as possible to the MMIC.

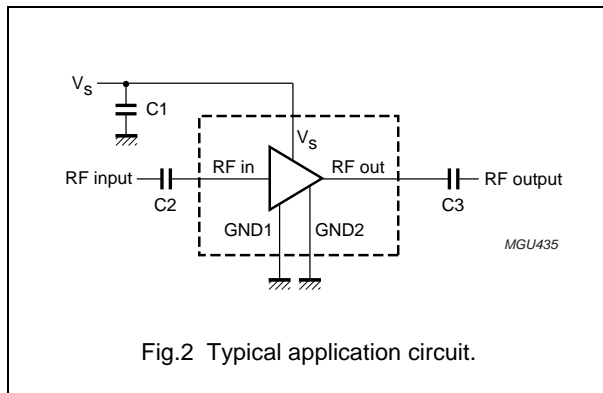
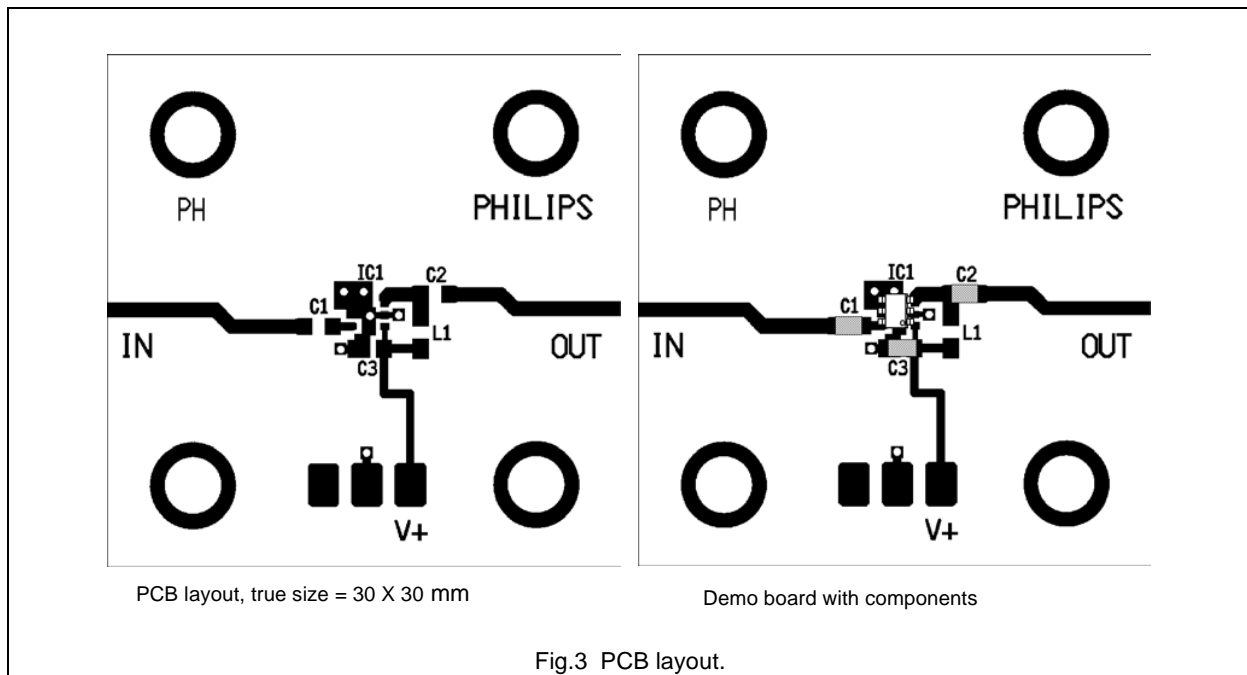


Figure 3 show the PCB layout, used for the standard demo board.

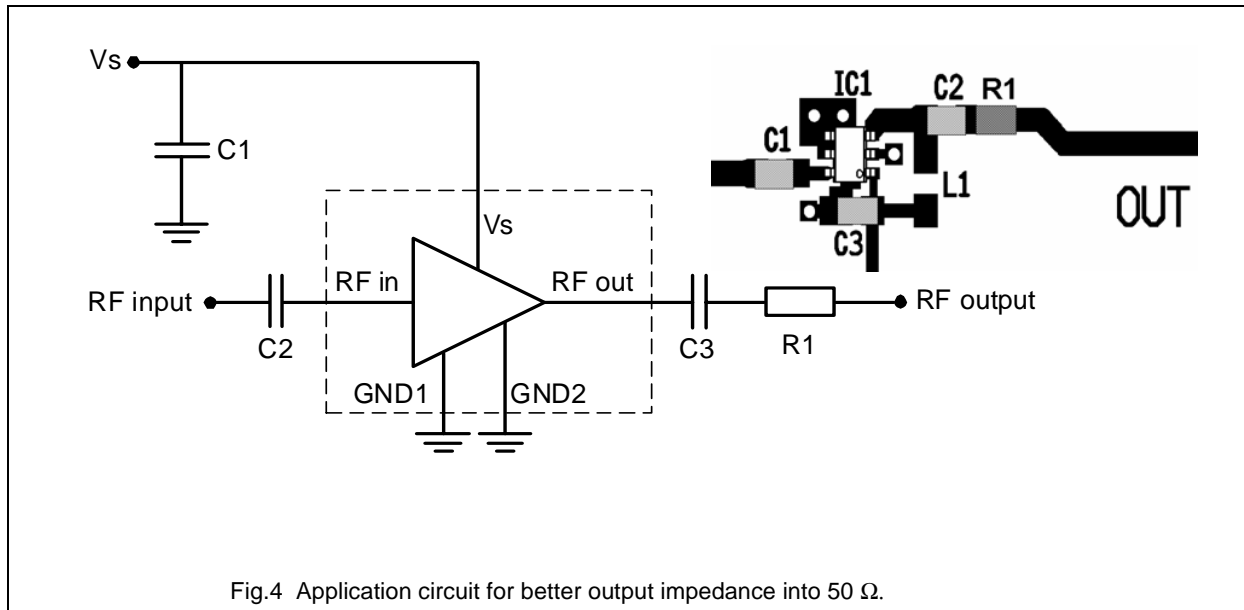


# MMIC wideband amplifier

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### Grounding and output impedance

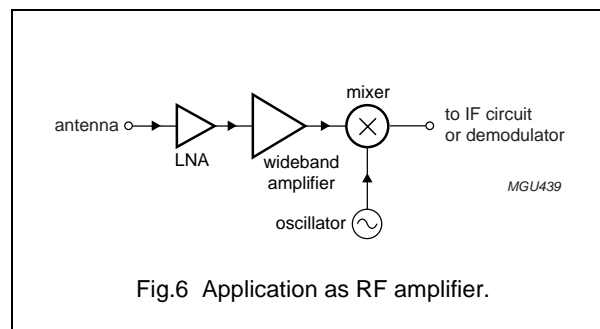
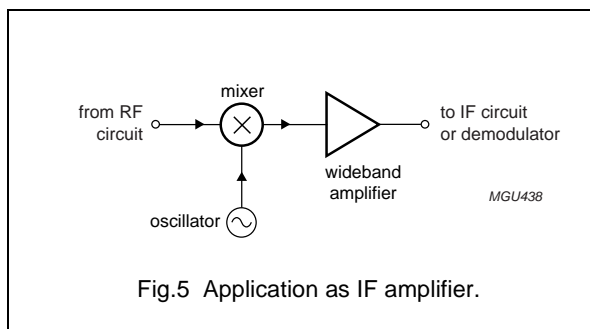
If the grounding is not optimal, the gain becomes less flat and the 50 Ω output matching becomes worse. If a better output matching to 50 Ω is required, a 12 Ω resistor (R1) can be placed in series with C3, see figure 4. This will significantly improve the output impedance, at the cost of 1 dB gain and 1 dB output power.



### APPLICATION EXAMPLES

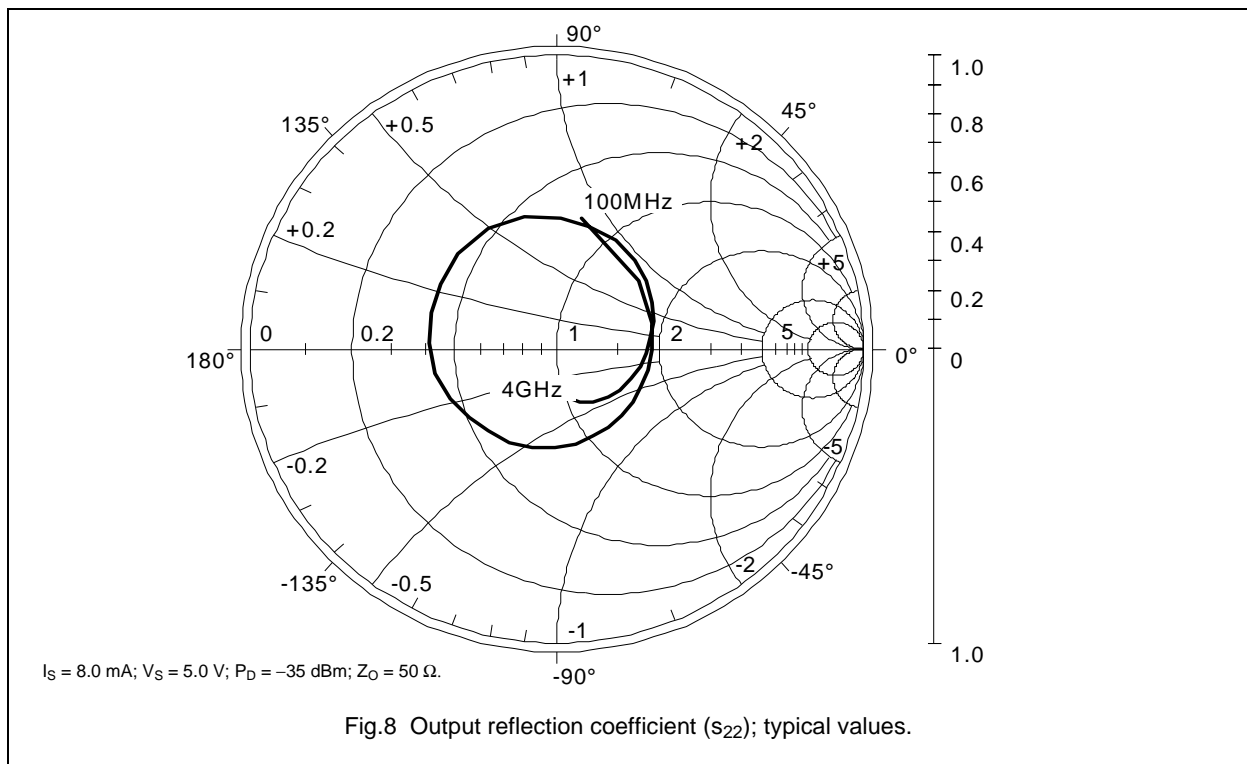
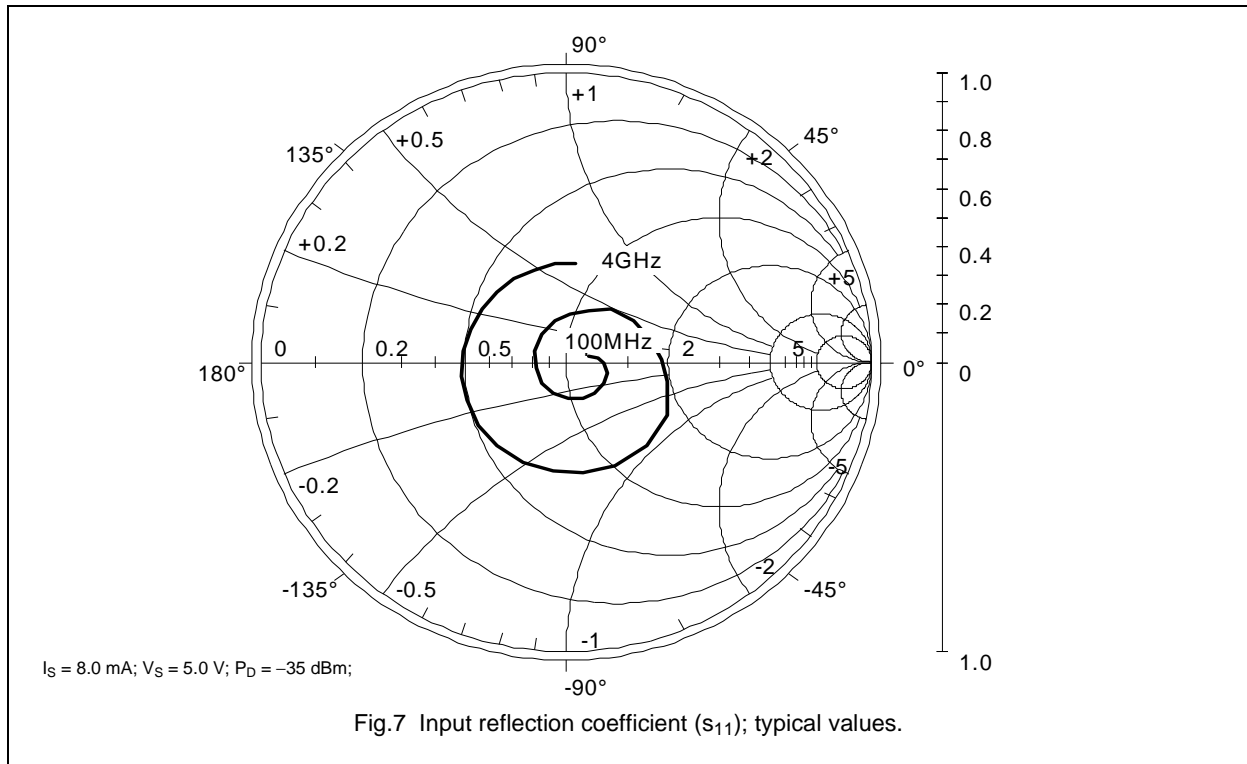
The MMIC is very suitable as IF amplifier in e.g. LNB's. The excellent wideband characteristics make it an ideal building block (figure 5).

As second amplifier after an LNA, the MMIC offers an easy matching, low noise solution (figure 6).



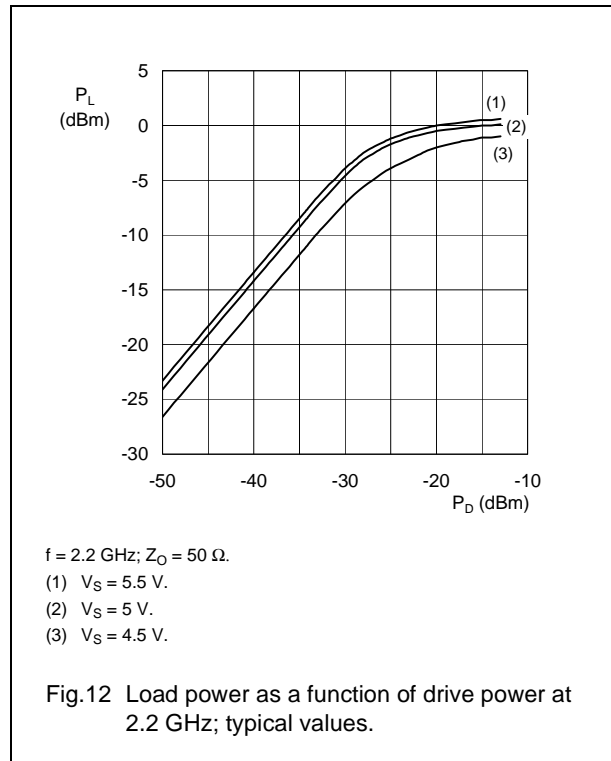
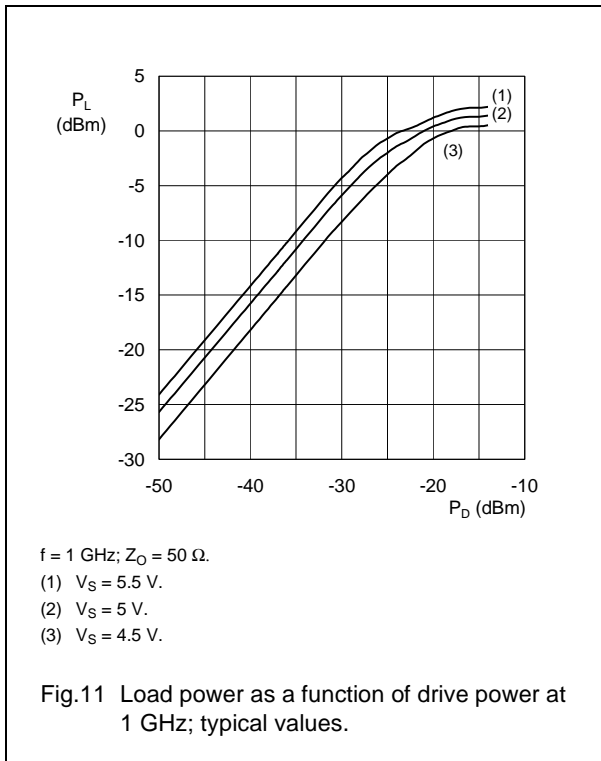
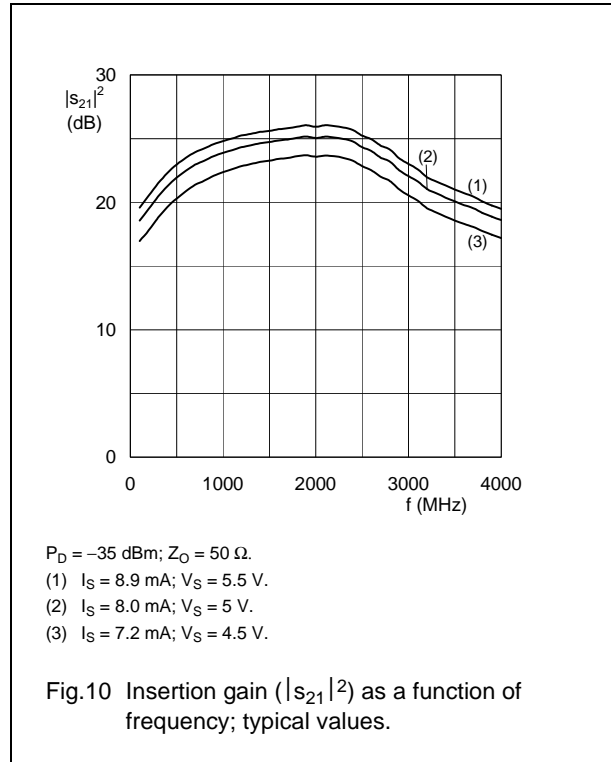
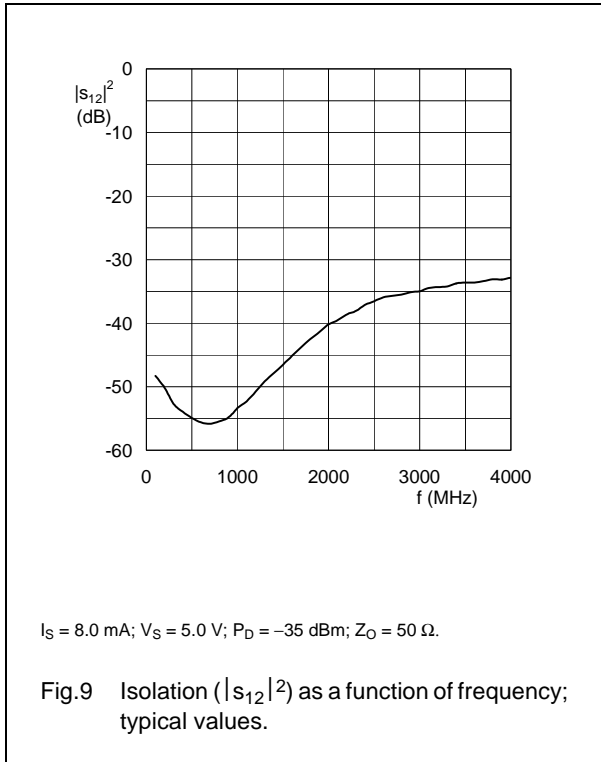
MMIC wideband amplifier

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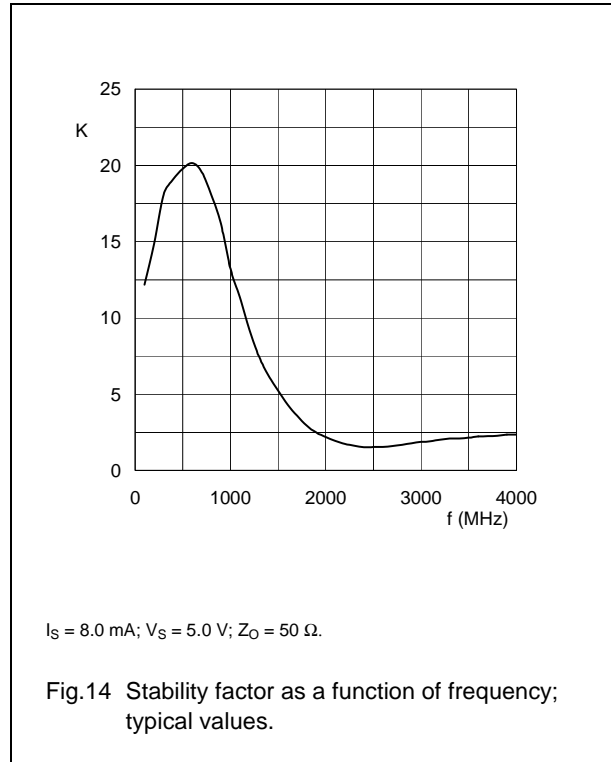
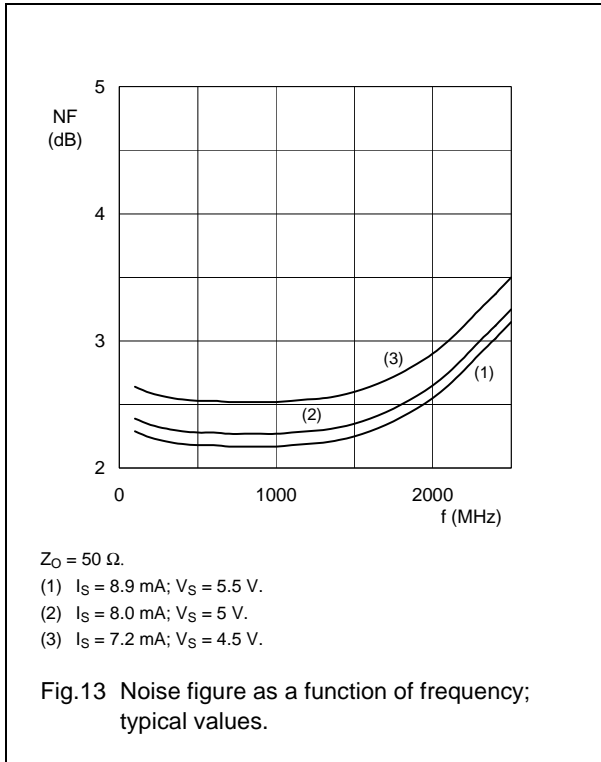
MMIC wideband amplifier

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MMIC wideband amplifier

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## MMIC wideband amplifier

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## Scattering parameters

 $V_S = 5.0 \text{ V}$ ;  $I_S = 8.0 \text{ mA}$ ;  $P_D = -35 \text{ dBm}$ ;  $Z_0 = 50 \text{ } \Omega$ ;  $T_{\text{amb}} = 25 \text{ } ^\circ\text{C}$ ;

f (MHz)	S <sub>11</sub>		S <sub>21</sub>		S <sub>12</sub>		S <sub>22</sub>		K-FACTOR
	MAGNITUDE (ratio)	ANGLE (deg)	MAGNITUDE (ratio)	ANGLE (deg)	MAGNITUDE (ratio)	ANGLE (deg)	MAGNITUDE (ratio)	ANGLE (deg)	
100	0.074378	13.78537	8.465495	22.90763	0.003859	-66.39435	0.450496	79.88713	12.2
200	0.076338	13.70153	9.420359	7.358555	0.003112	-122.2687	0.354179	40.70919	14.9
400	0.123748	-1.402521	11.56481	-14.92222	0.002011	-40.5142	0.312568	-0.3804	19.1
600	0.145511	-31.32646	13.31271	-37.77988	0.001659	-156.393	0.3038	-25.36808	20.2
800	0.134956	-67.10955	14.56872	-61.08808	0.00169	-164.4454	0.30873	-46.7704	18.1
1000	0.114063	-111.2495	15.61733	-84.67015	0.002146	-174.8593	0.319208	-68.71787	13.2
1200	0.101959	-168.8557	16.45625	-107.9167	0.002901	139.8136	0.335623	-91.58398	9.2
1400	0.125656	129.9717	17.05668	-131.63	0.004053	123.527	0.353582	-116.5485	6.2
1600	0.16736	85.791	17.49643	-155.2301	0.005545	107.0763	0.366893	-140.7537	4.3
1800	0.234721	51.43065	17.90167	-179.6656	0.007498	105.9423	0.404064	-167.9683	2.9
2000	0.285944	16.46701	17.86635	155.5993	0.009779	90.10168	0.42512	163.3173	2.2
2200	0.339673	-11.74152	17.96498	130.5601	0.011736	75.19814	0.459194	135.039	1.7
2400	0.393746	-47.58817	17.32414	103.3297	0.013927	53.10814	0.459988	103.1106	1.5
2600	0.384353	-81.55786	15.87927	77.84766	0.015937	21.70136	0.428158	75.83004	1.5
2800	0.376183	-112.353	14.44081	52.77053	0.016795	4.656224	0.393701	50.16202	1.7
3000	0.358586	-142.5801	12.67831	30.51455	0.01786	-19.19006	0.3497	26.66791	1.9
3200	0.345562	-171.7261	11.27597	10.04765	0.019217	-32.22469	0.30875	6.504047	2.0
3400	0.33312	160.2254	10.43483	-9.842264	0.020551	-49.16136	0.279672	-12.63121	2.1
3600	0.331268	133.8644	9.743293	-30.36495	0.020908	-59.65434	0.248479	-33.64811	2.2
3800	0.337502	108.48	9.072149	-50.7401	0.022136	-78.78085	0.21362	-56.42401	2.3
4000	0.344645	84.75183	8.513716	-71.86536	0.022792	-94.87525	0.168643	-80.24833	2.4

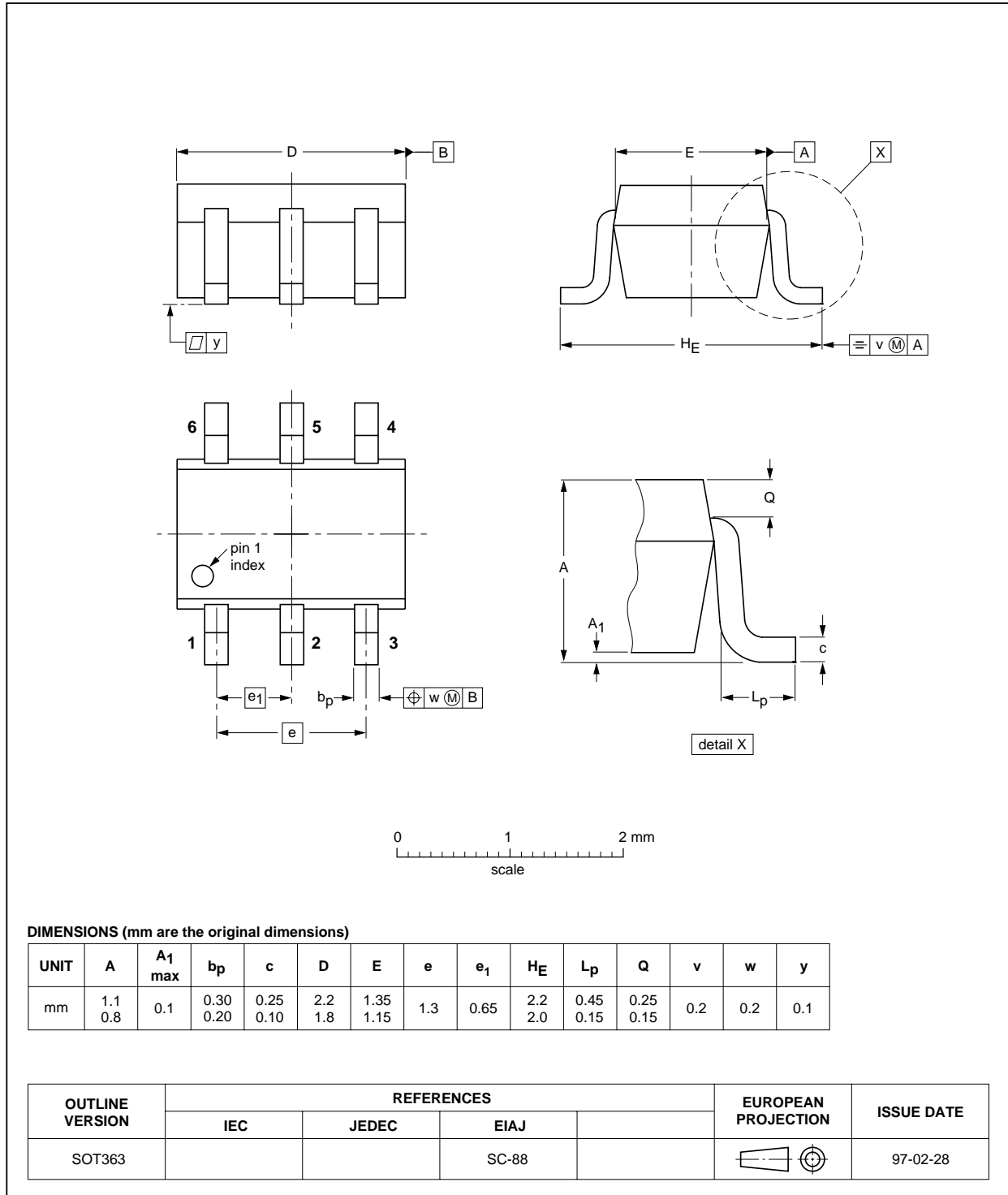
MMIC wideband amplifier

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PACKAGE OUTLINE

Plastic surface mounted package; 6 leads

SOT363



## MMIC wideband amplifier

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## DATA SHEET STATUS

LEVEL	DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)(3)</sup>	DEFINITION
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